Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass

Overall Length:

0.210 inches

Overall Height:

0.210 inches

Overall Width:

0.135 inches

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

8.4 breakdown voltage, dc

Current Rating Per Characteristic:

60.00 milliamperes source cutoff current preset and 0.10 microamperes forward current, average major

Power Rating Per Characteristic:

150.0 milliwatts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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